INSTITUTE OF AERONAUTICAL ENGINEERING
(Autonomous)
Dundigal, Hyderabad - 500043

## MODEL QUESTION PAPER-II

B.Tech V Semester End Examinations, November - 2019

Regulation: IARE-R18

## BASIC ELECTRONICS ENGINEERING <br> (Civil Engineering)

## Time: 3 Hours

Max Marks: 70

> Answer any ONE question from each Module
> All questions carry equal marks
> All parts of the question must be answered in one place only

MODULE - I
1 a) With neat diagram explain the working of a half wave rectifier.
b) Determine the values of forward current in the case of P-N junction diode, with Io= $10 \mu \mathrm{~A}$
$\mathrm{Vf}=0.8 \mathrm{~V}$ at $\mathrm{T}=3000 \mathrm{~K}$. Assume silicon diode?
a) Explain with neat sketches how a zener diode is used a regulator?
b) Explain with neat sketches how avalanche breakdown occurs in a pn diode.

## MODULE - II

3 a) Explain how FET behaves as a voltage variable resistor
b) Draw the circuit diagram of a fixed bias and derive expression for Stability factor.

4 a) Enumerate the differences between BJT and FET.
b) The reverse leakage current of the transistor when connected in CB configuration is $0.2 \mu \mathrm{~A}$ while it is $18 \mu \mathrm{~A}$ when the same transistor is connected in CE configuration. Determine $\alpha$ and $\beta$ of the transistor?

## MODULE - III

[^0]a) Explain the Voltage Follower with neat diagram
b) Describe the following terms in an OP-AMP. 1. Input Bias current 2. Input offset voltage 3. Input offset current

## MODULE - IV

7 a) Explain each block of the functional block diagram of 555 timer and list the advantages of 555 timer.
b) Define resolution. How many levels are possible in a two bit DAC what is its resolution if the output range is 0 to 3 V .
a) Discuss about the flash type converter with a neat block diagram
b) What is DAC? Calculate the values of the LSB,MSB and full scale output for an 8 bit DAC for the 0 to 10 V range.

## MODULE - V

9
a) Explain the gray to binary and binary- to- gray conversion with examples
b) Give the Boolean expressions, symbols and truth tables for following gates i) AND ii) NOR iii) EXOR iv) OR v) EX-NOR.

10
a) Simplify using postulates and theorems of Boolean algebra i) $\left(\mathrm{X}^{\prime}+\mathrm{Y}^{\prime}+\mathrm{XY}\right)\left(\mathrm{X}^{\prime}+\mathrm{Y}^{\prime}\right) \mathrm{X}^{\prime} \mathrm{Y} \quad$ ii) $(\mathrm{AB}+\mathrm{C}+\mathrm{D})\left(\mathrm{C}^{\prime}+\mathrm{D}\right)\left(\mathrm{C}^{\prime}+\mathrm{D}+\mathrm{E}\right)$
b) Convert (4085) ${ }_{10}$ into base-4 and obtain its $9^{\circ \circ} \mathrm{s}$ complement.

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## COURSE OBJECTIVES:

| The course should enable the students to: |  |
| :---: | :--- |
| I | Introduce components such as diodes, BJTs and FETs. |
| II | Know the applications of components. |
| III | Understand common forms of number representation in logic circuits. |
| IV | Be acquainted to principles and characteristics of op-amp and apply the techniques for the design <br> of comparators, instrumentation amplifier, integrator, differentiator. |

## COURSE OUTCOMES (COs):

| CO 1 | Describe the concept of diode and its applications. |
| :--- | :--- |
| CO 2 | Describe the operation of various transistors, FETs and their biasing methods. |
| CO 3 | Understand the concept of operational amplifier with analysis of applications. |
| CO 4 | Analysis of 555 timer IC for multivibrators and op-amp data converters. |
| CO 5 | Explore the digital number systems and various digital logic circuits. |

## COURSE LEARNING OUTCOMES (CLOs):

| AECB01.01 | Understand the basic concept of PN junction diode. |
| :--- | :--- |
| AECB01.02 | Analyze the characteristics of diode for ideal and practical conditions. |
| AECB01.03 | Understand the applications of diode in rectifiers with and without filters. |
| AECB01.04 | Understand the concept of breakdown mechanism in diodes with applications of Zener breakdown <br> diodes. |
| AECB01.05 | Describe the classification family table of various transistors. |
| AECB01.06 | Describe the concept of Bipolar Junction transistor with various modes of operation. |
| AECB01.07 | Understand the concept of transistor biasing with voltage divider bias. |
| AECB01.08 | Understand the construction and working of Field Effect Transistor(FET). |
| AECB01.09 | Understand the concept of Metal Oxide Semiconductor FET. |
| AECB01.10 | Illustrate the basic CMOS circuits. |
| AECB01.11 | Understand the basic concepts of operational amplifiers. |
| AECB01.12 | Analyze the parameters of practical and ideal op-amps. |
| AECB01.13 | Understand the concept of virtual ground in op-amps. |
| AECB01.14 | Perform basic arithmetic operations on voltages using opamps. |
| AECB01.15 | Examine the working of op-amp as differentiator, integrator, comparator and buffer. |
| AECB01.16 | Understand the internal block diagram of 555 timer IC. |
| AECB01.17 | Examine the working of 555 timer as astable and monostablemultivibrator. |
| AECB01.18 | Understand the principle of data conversions with terminology. |
| AECB01.19 | Analyze the A/D converters. |
| AECB01.20 | Analyze the resistor ladder D/A converters. |
| AECB01.21 | Perform calculations in different number systems. |


| AECB01.22 | Understand the basic concepts of Boolean algebra and combinational logic circuits. |
| :---: | :--- |
| AECB01.23 | Understand the basic sequential logic circuits. |
| AECB01.24 | Understand counters, registers. |

## MAPPING OF SEMESTER END EXAMINATION - COURSE OUTCOMES

| $\begin{array}{\|c\|} \hline \text { SEE } \\ \text { Question } \\ \text { No } \\ \hline \end{array}$ |  | Course Learning Outcomes |  | Course Outcomes | $\qquad$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 1 | a | AECB01.01 | Understand the basic concept of PN junction diode. | CO 1 | Understand |
|  | b | AECB01.01 | Understand the basic concept of PN junction diode. | CO 1 | Apply |
| 2 | a | AECB01.04 | Understand the concept of breakdown mechanism in diodes with applications of Zener breakdown diodes. | CO 1 | Understand |
|  | b | AECB01.02 | Understand the applications of diode in rectifiers with and without filters. | CO 1 | Understand |
| 3 | a | AECB01.09 | Understand the concept of Metal Oxide Semiconductor FET. | CO 2 | Understand |
|  | b | AECB01.08 | Understand the construction and working of Field Effect Transistor(FET). | CO 2 | Remember |
| 4 | a | AECB01.10 | Illustrate the basic CMOS circuits | CO 2 | Understand |
|  | b | AECB01.07 | Understand the concept of transistor biasing with voltage divider bias. | CO 2 | Understand |
| 5 | a | AECB01.13 | Understand the concept of virtual ground in op-amps. | CO 3 | Understand |
|  | b | AECB01.11 | Understand the basic concepts of operational amplifiers. | CO 3 | Apply |
| 6 | a | AECB01.12 | Analyze the parameters of practical and ideal op-amps. | CO 3 | Understand |
|  | b | AECB01.14 | Perform basic arithmetic operations on voltages using opamps. | CO 3 | Remember |
| 7 | a | AECB01.17 | Examine the working of 555 timer as astable and monostablemultivibrator. | CO 4 | Understand |
|  | b | AECB01.17 | Examine the working of 555 timer as astable and monostable multivibrator. | CO 4 | Apply |
| 8 | a | AECB01.19 | Analyze the A/D converters. | CO 4 | Understand |
|  | b | AECB01.18 | Understand the principle of data conversions with terminology. | CO 4 | Apply |
| 9 | a | AECB01.22 | Understand the basic concepts of Boolean algebra and combinational logic circuits. | CO 5 | Understand |
|  | b | AECB01.22 | Understand the basic concepts of Boolean algebra and combinational logic circuits. | CO 5 | Understand |
| 10 | a | AECB01.22 | Understand the basic concepts of Boolean algebra and combinational logic circuits. | CO 5 | Understand |
|  | b | AECB01.21 | Perform calculations in different number systems. | CO 5 | Apply |


[^0]:    a) With circuit and waveforms explain the application of OPAMP as Differentiator and write the advantages of practical differentiator
    b) The input signal to an op-amp is $0.03 \sin (1.5 \times 105)$ t. calculate maximum gain of an op-amp with the slew rate of $0.4 \mathrm{~V} / \mu \mathrm{sec}$.

